

Dual P-Channel MOSFET, 600 mA, 20 V PowerTrench, 6-Pin SOT-363 (SC-70) ON Semiconductor

Manufacturers	ON Semiconductor, LLC
Package/Case	SC-70-6
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for FDG6306P or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

This P-Channel 2.5V specified MOSFET is a rugged gate version of an advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V – 12V).

Application

ONSEMI

Related Products



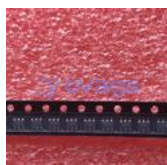
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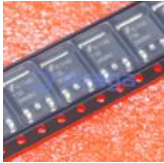
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